## NSN 5961-00-434-0852

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-434-0852 **Inclosure Material:** Glass **Overall Length:** Between 0.140 inches and 0.300 inches **Terminal Length:** Between 0.900 inches and 1.500 inches **Overall Diameter:** Between 0.090 inches and 0.145 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 105.0 breakdown voltage, dc **Current Rating Per Characteristic:** 2.00 milliamperes forward current, average peak **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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